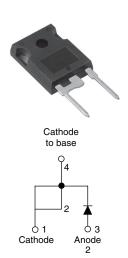


#### Vishay High Power Products

# HEXFRED® Ultrafast Soft Recovery Diode, 25 A



TO-247AC modified

PRODUCT SUMMARY				
V <sub>R</sub>	600 V			
V <sub>F</sub> at 25 A at 25 °C	1.7 V			
I <sub>F(AV)</sub>	25 A			
t <sub>rr</sub> (typical)	23 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub> (typical)	112 nC			
dl <sub>(rec)M</sub> /dt (typical)	250 A/μs			
I <sub>RRM</sub>	10 A			

#### **FEATURES**

- · Ultrafast recovery
- · Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- · Specified at operating conditions
- · Lead (Pb)-free
- · Designed and qualified for industrial level

# Pb-free Available

ROHS'

#### **BENEFITS**

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- Reduced snubbing
- · Reduced parts count

#### **DESCRIPTION**

HFA25PB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A continuous current, the HFA25PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA25PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V <sub>R</sub>		600	V	
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	25		
Single pulse forward current	I <sub>FSM</sub>		225	Α	
Maximum repetitive forward current	I <sub>FRM</sub>		100		
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	151	W	
		T <sub>C</sub> = 100 °C	60		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C	

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<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

### HFA25PB60PbF

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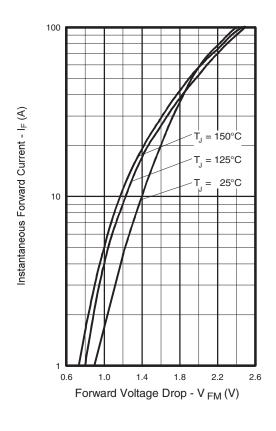
<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	-	-	
		I <sub>F</sub> = 25 A		=	1.3	1.7	V
Maximum forward voltage	$V_{FM}$	I <sub>F</sub> = 50 A	See fig. 1	=	1.5	2.0	
		I <sub>F</sub> = 25 A, T <sub>J</sub> = 125 °C		-	1.3	1.7	
Maximum reverse		$V_R = V_R$ rated	Coo fig. 0	-	1.5	20	
leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 0.8 x V <sub>R</sub> rated	See fig. 2	=	600	2000	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	See fig. 3	=	55	100	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		-	12	-	nH

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	23	-	ns
	everse recovery time ee fig. 5, 10		-	50	75		
000 lig. 0, 10		-	105	160			
Peak recovery current See fig. 6, 10	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 25 A	-	4.5	10	А
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	8.0	15	
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	112	375	nC
See fig. 7, 10	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	420	1200	
Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8, 10	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	250	-	A/us
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	160	-	Αίμο

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.83	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-	
Weight			-	6.0	-	g
vveigni		-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅cm (lbf ⋅in)
Marking device		Case style TO-247AC modified (JEDEC)	HFA25PB60			



## HEXFRED® Vishay High Power Products Ultrafast Soft Recovery Diode, 25 A



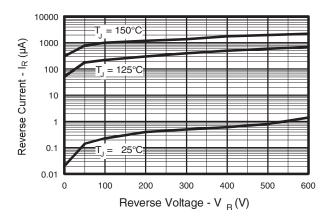


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

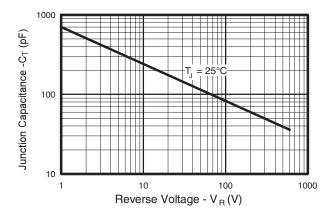


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

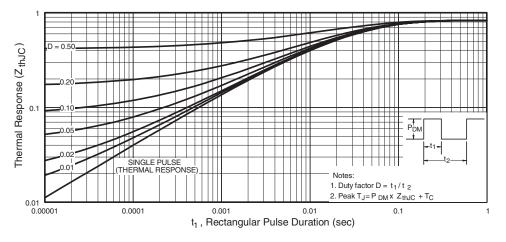


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

### Vishay High Power Products

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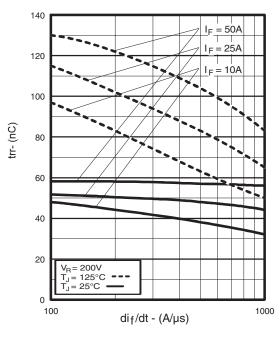


Fig. 5 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

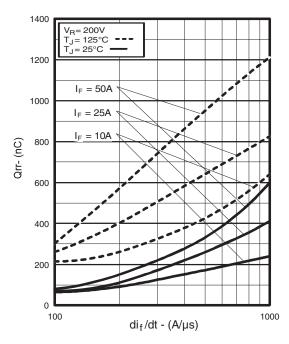


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

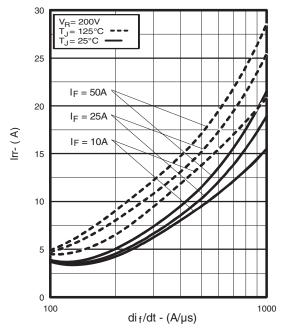


Fig. 6 - Typical Recovery Current vs. dI<sub>F</sub>/dt

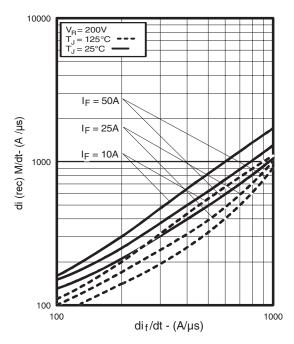


Fig. 8 - Typical dI<sub>(rec)M</sub>/dt vs. dI<sub>F</sub>/dt

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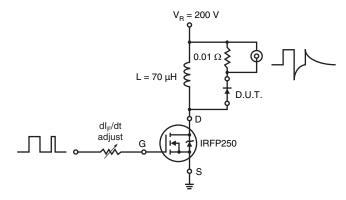
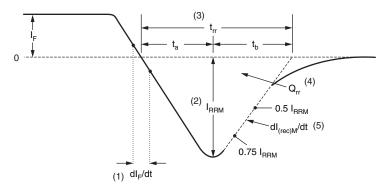


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

#### HFA25PB60PbF

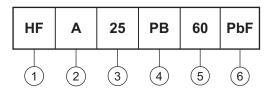
### Vishay High Power Products

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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - HEXFRED® family

Process designator: A = Electron irradiated

B = Platinum diffused

**3** - Current rating (25 = 25 A)

- Package outline (PB = TO-247, 2 pins)

5 - Voltage rating (60 = 600 V)

- None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			

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